

PSMNR70-30YLH

N-channel 30 V, 0.82 m Ω , 300 A logic level MOSFET in LFPAK56 using NextPowerS3 technology

12 November 2019

Product data sheet

1. General description

Logic level gate drive N-channel enhancement mode MOSFET in LFPAK56 package optimized for low R_{DSon} . Low I_{DSS} leakage even when hot, high efficiency and high current rated to 300 A, optimized for DC load switch and hot-swap applications.

2. Features and benefits

- 100% avalanche tested at I_(AS) = 190 A
- Optimized for low R_{DSon}
- Low leakage < 1 µA at 25 °C
- · Low spiking and ringing for low EMI designs
- · Optimized for 4.5 V gate drive
- · Copper-clip for low parasitic inductance and resistance
- High reliability LFPAK package, qualified to 175 °C
- Wave solderable; exposed leads for optimal solder coverage and visual solder inspection

3. Applications

- Hot swap
- e-fuse
- Power OR-ing
- DC switch / Load switch
- Battery protection
- · Brushed and BLDC (brushless) motor control
- Synchronous rectification in AC-DC and DC-DC applications

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	-	30	V	
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	-	300	Α	
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	-	268	W	
Tj	junction temperature			-55	-	175	°C	
Static characte	eristics							
R _{DSon}	drain-source on-state resistance	$V_{GS} = 10 \text{ V}; I_D = 25 \text{ A}; T_j = 25 ^{\circ}\text{C};$ Fig. 10		-	0.66	0.82	mΩ	
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10		-	0.86	1.1	mΩ	
Dynamic chara	Dynamic characteristics							
Q_{GD}	gate-drain charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		2.9	16	32	nC	
Q _{G(tot)}	total gate charge	Fig. 12; Fig. 13		21	46	76	nC	



Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Source-drain diode							
S	softness factor	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; Fig. 16$		-	0.96	-	

^{[1] 300}A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	S	source	mb	D
2	S	source	<u> </u>	
3	S	source		G—(in A)
4	G	gate	(111111	mbb076 S
mb	D	mounting base; connected to drain	LFPAK56; Power- SO8 (SOT669)	

6. Ordering information

Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
PSMNR70-30YLH	LFPAK56; Power-SO8	plastic, single-ended surface-mounted package; 4 terminals	SOT669			

7. Marking

Table 4. Marking codes

Type number	Marking code
PSMNR70-30YLH	H7030L

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{DS}	drain-source voltage	25 °C ≤ T _j ≤ 175 °C		-	30	V
V_{DGR}	drain-gate voltage	25 °C ≤ T_j ≤ 175 °C; R_{GS} = 20 kΩ		-	30	V
V_{GS}	gate-source voltage			-20	20	V
P _{tot}	total power dissipation	T _{mb} = 25 °C; <u>Fig. 1</u>		-	268	W
I _D	drain current	V _{GS} = 10 V; T _{mb} = 25 °C; <u>Fig. 2</u>	[1]	-	300	А
		V _{GS} = 10 V; T _{mb} = 100 °C; <u>Fig. 2</u>		-	281	Α
I _{DM}	peak drain current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 °C$; Fig. 3		-	1589	А
T _{stg}	storage temperature			-55	175	°C
Tj	junction temperature			-55	175	°C

Symbol	Parameter	Conditions		Min	Max	Unit
T _{sld(M)}	peak soldering temperature			-	260	°C
Source-drain die	ode					
Is	source current	T _{mb} = 25 °C		-	268	А
I _{SM}	peak source current	pulsed; $t_p \le 10 \mu s$; $T_{mb} = 25 ^{\circ}C$		-	1589	А
Avalanche rugg	edness					
E _{DS(AL)S}		I_D = 25 A; $V_{sup} \le 30$ V; R_{GS} = 50 Ω; V_{GS} = 10 V; $T_{j(init)}$ = 25 °C; unclamped; t_p = 4.9 ms	[2]	-	2.4	J
I _{AS}	non-repetitive avalanche current	$V_{sup} \le 30 \text{ V}; V_{GS} = 10 \text{ V}; T_{j(init)} = 25 \text{ °C};$ $R_{GS} = 50 \Omega$	[2]	-	190	А

^{[1] 300}A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

^[2] Protected by 100% test

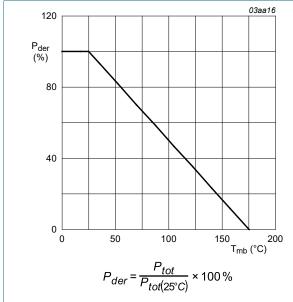
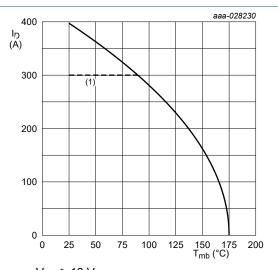
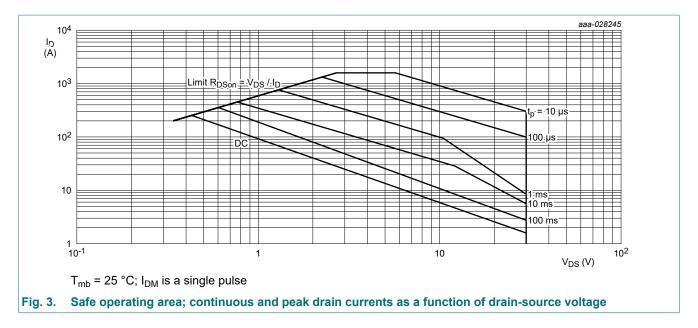


Fig. 1. Normalized total power dissipation as a function of mounting base temperature



 $V_{GS} \ge 10 \text{ V}$ (1) 300A continuous current has been successfully demonstrated during application tests. Practically the current will be limited by PCB, thermal design and operating temperature.

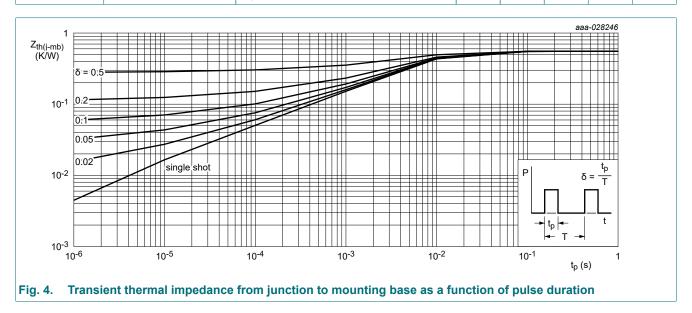
Fig. 2. Continuous drain current as a function of mounting base temperature



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	Fig. 4	-	0.48	0.56	K/W
R _{th(j-a)}	thermal resistance from	Fig. 5	-	42	-	K/W
junction to ambient	Fig. 6	-	85	-	K/W	



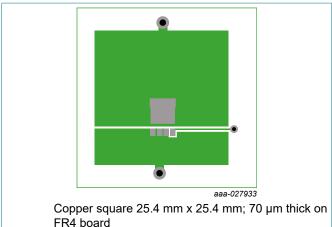
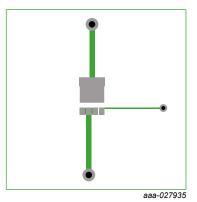


Fig. 5. PCB layout for thermal resistance from junction to ambient



70 µm thick copper on FR4 board

Fig. 6. PCB layout with minimum footprint for thermal resistance from junction to ambient

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static charac	teristics					
V _{(BR)DSS}	drain-source	I _D = 250 μA; V _{GS} = 0 V; T _j = 25 °C	30	-	-	V
	breakdown voltage	I _D = 250 μA; V _{GS} = 0 V; T _j = -55 °C	27	-	-	V
V _{GS(th)}	gate-source threshold voltage	$I_D = 2 \text{ mA}; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	1.2	1.5	2.2	V
$\Delta V_{GS(th)}/\Delta T$	gate-source threshold voltage variation with temperature	25 °C ≤ T _j ≤ 150 °C	-	-4.4	-	mV/K
I _{DSS}	drain leakage current	V _{DS} = 24 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
		V _{DS} = 24 V; V _{GS} = 0 V; T _j = 125 °C	-	6.4	-	μΑ
I _{GSS}	gate leakage current	V _{GS} = 16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
		V _{GS} = -16 V; V _{DS} = 0 V; T _j = 25 °C	-	-	100	nA
R _{DSon}	drain-source on-state resistance	V_{GS} = 10 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	0.66	0.82	mΩ
		V _{GS} = 10 V; I _D = 25 A; T _j = 150 °C; Fig. 11	-	-	1.5	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 25 °C; Fig. 10	-	0.86	1.1	mΩ
		V_{GS} = 4.5 V; I_D = 25 A; T_j = 150 °C; Fig. 11	-	-	2	mΩ
R _G	gate resistance	f = 1 MHz; T _j = 25 °C	0.5	1.3	3.3	Ω
Dynamic cha	racteristics					
Q _{G(tot)}	total gate charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V; Fig. 12; Fig. 13	21	46	76	nC
		I _D = 25 A; V _{DS} = 15 V; V _{GS} = 10 V; Fig. 12; Fig. 13	43	95	157	nC
		I _D = 0 A; V _{DS} = 0 V; V _{GS} = 10 V	-	50	-	nC

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Q _{GS}	gate-source charge	I _D = 25 A; V _{DS} = 15 V; V _{GS} = 4.5 V;		3	11	21	nC
Q _{GS(th)}	pre-threshold gate- source charge	Fig. 12; Fig. 13		2.2	8	15	nC
Q _{GS(th-pl)}	post-threshold gate- source charge			0.86	3.2	6.1	nC
Q _{GD}	gate-drain charge			2.9	16	32	nC
$V_{GS(pl)}$	gate-source plateau voltage	I _D = 25 A; V _{DS} = 15 V; <u>Fig. 12</u> ; <u>Fig. 13</u>		-	2.3	-	V
C _{iss}	input capacitance	V _{DS} = 15 V; V _{GS} = 0 V; f = 1 MHz;		3284	5473	8210	pF
C _{oss}	output capacitance	T _j = 25 °C; <u>Fig. 14</u>		1702	2836	4254	pF
C _{rss}	reverse transfer capacitance			129	478	1147	pF
t _{d(on)}	turn-on delay time	$V_{DS} = 15 \text{ V}; R_L = 0.6 \Omega; V_{GS} = 4.5 \text{ V};$		-	28	-	ns
t _r	rise time	$R_{G(ext)} = 5 \Omega$		-	51	-	ns
t _{d(off)}	turn-off delay time			-	61	-	ns
t _f	fall time			-	45	-	ns
Q _{oss}	output charge	$V_{GS} = 0 \text{ V}; V_{DS} = 15 \text{ V}; f = 1 \text{ MHz};$ $T_j = 25 \text{ °C}$		-	62	-	nC
Source-drai	in diode						
V_{SD}	source-drain voltage	I _S = 25 A; V _{GS} = 0 V; T _j = 25 °C; <u>Fig. 15</u>		-	0.75	1	V
t _{rr}	reverse recovery time	$I_S = 25 \text{ A}; dI_S/dt = -100 \text{ A/}\mu\text{s}; V_{GS} = 0 \text{ V};$		-	46	-	ns
Q _r	recovered charge	V _{DS} = 15 V; <u>Fig. 16</u>	[1]	-	50	-	nC
t _a	reverse recovery rise time			-	23.4	-	ns
t _b	reverse recovery fall time			-	22.5	-	ns
S	softness factor			-	0.96	-	
		1					

[1] includes capacitive recovery

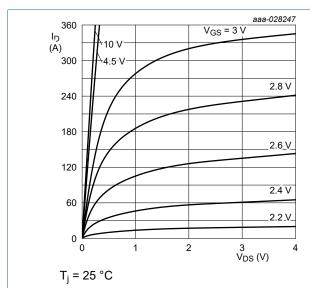


Fig. 7. Output characteristics; drain current as a function of drain-source voltage; typical values

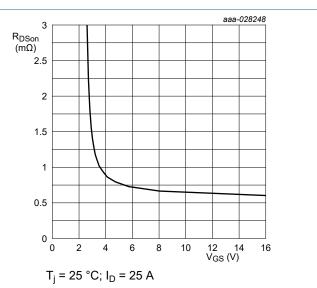


Fig. 8. Drain-source on-state resistance as a function of gate-source voltage; typical values

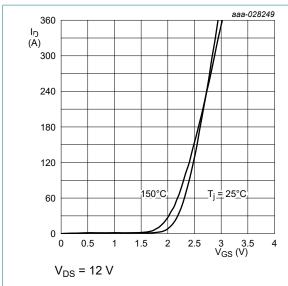


Fig. 9. Transfer characteristics; drain current as a function of gate-source voltage; typical values

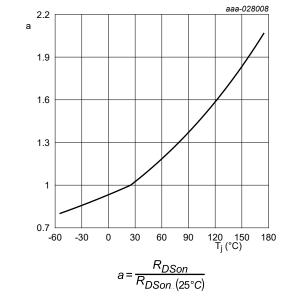


Fig. 11. Normalized drain-source on-state resistance factor as a function of junction temperature

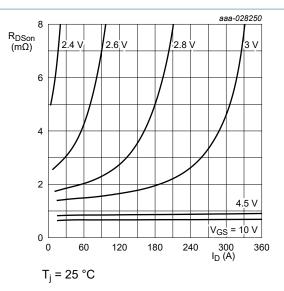


Fig. 10. Drain-source on-state resistance as a function of drain current; typical values

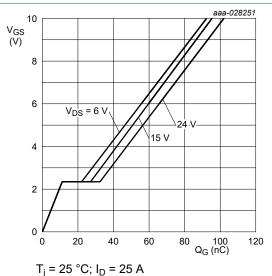


Fig. 12. Gate-source voltage as a function of gate charge; typical values

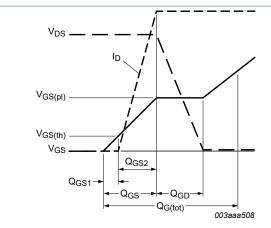
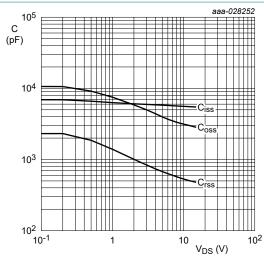


Fig. 13. Gate charge waveform definitions



 $V_{GS} = 0 V$; f = 1 MHz

Fig. 14. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

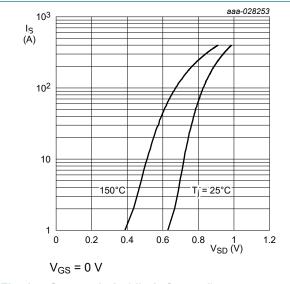


Fig. 15. Source-drain (diode forward) current as a function of source-drain (diode forward) voltage; typical values

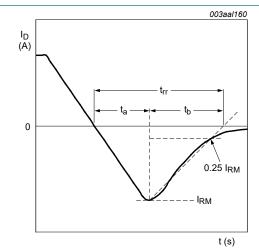
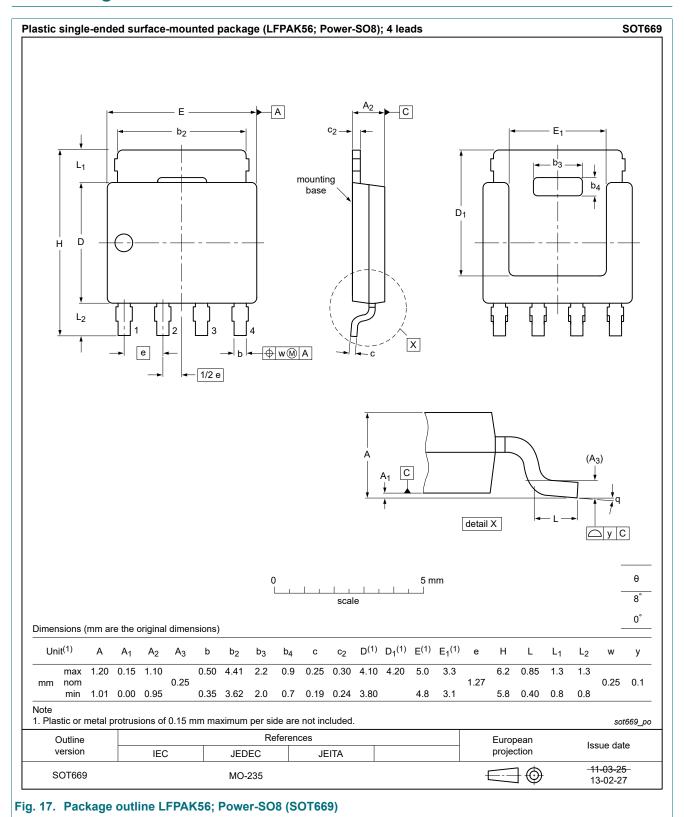
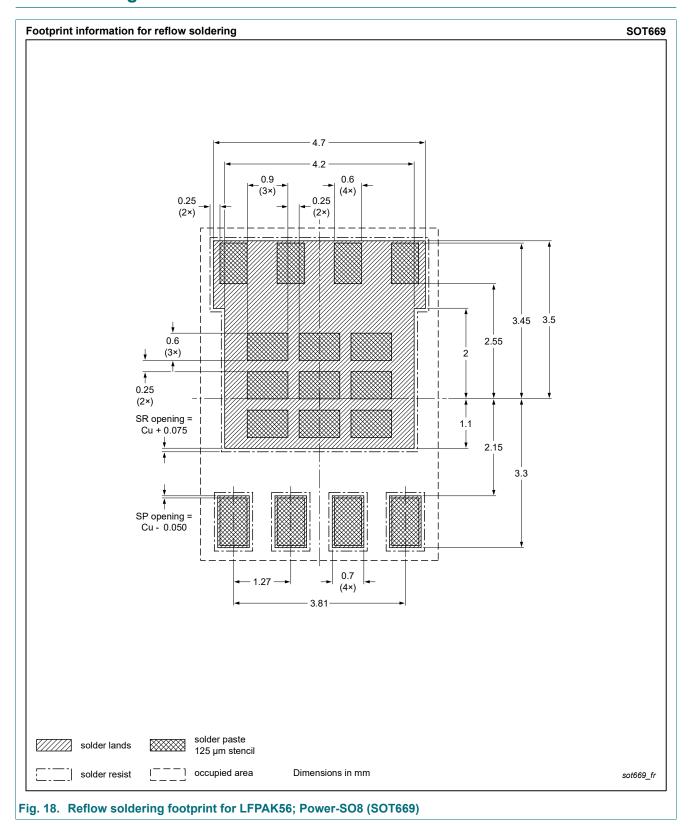


Fig. 16. Reverse recovery timing definition

11. Package outline



12. Soldering



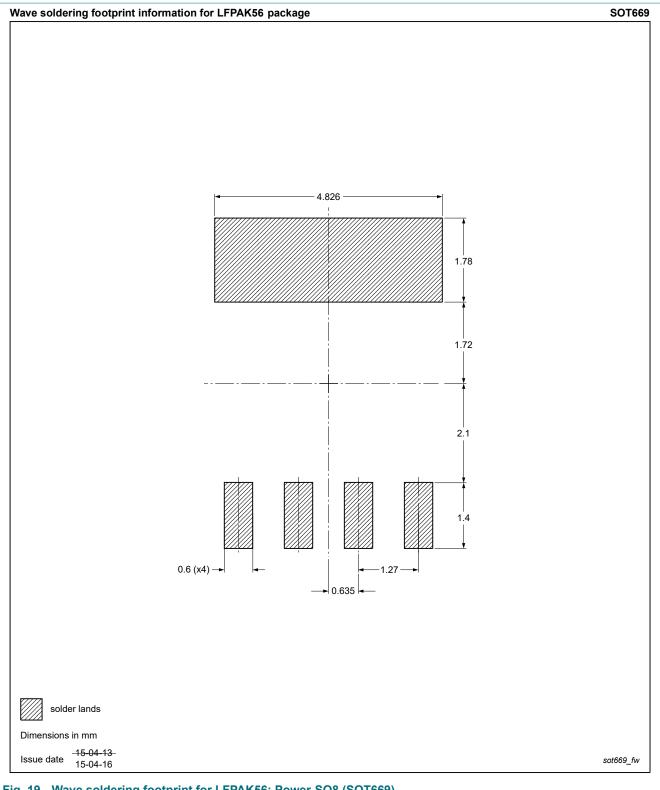


Fig. 19. Wave soldering footprint for LFPAK56; Power-SO8 (SOT669)

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